

isc N-Channel MOSFET Transistor

R6535ENZ1

FEATURES

- Drain Current –I_D= 35A@ T_C=25 °C
- Drain Source Voltage-
 - : V_{DSS}=650V(Min)
- Static Drain-Source On-Resistance
 - : $R_{DS(on)} = 115m \Omega (Max)$
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

DESCRIPTION

• Designed for use in switch mode power supplies and general purpose applications.

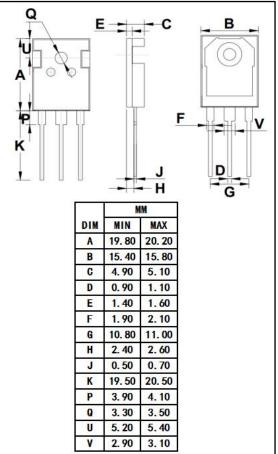
pin 1.Gate 2.Drain 3.Source TO-247 package

ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

SYMBOL	PARAMETER	VALUE	UNIT
V _{DSS}	Drain-Source Voltage	650	٧
V_{GS}	Gate-Source Voltage-Continuous	±20	٧
I _D	Drain Current-Continuous	35	Α
I _{DM}	Drain Current-Single Pluse	105	Α
P _D	Total Dissipation @T _C =25℃	102	W
TJ	Max. Operating Junction Temperature	x. Operating Junction Temperature 150	
T _{stg}	Storage Temperature	mperature -55~150	

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
R _{th j-c}	Thermal Resistance, Junction to Case	1.25	°C/W





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ELECTRICAL CHARACTERISTICS

T_C=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	MAX	UNIT
V _{(BR)DSS}	Drain-Source Breakdown Voltage	V _{GS} = 0; I _D = 1mA	650		V
V _{GS(th)}	Gate Threshold Voltage	V _{DS} = V _{GS} ; I _D =1.21mA	2	4	V
R _{DS(on)}	Drain-Source On-Resistance	V _{GS} = 10V; I _D = 18.1A		115	mΩ
I _{GSS}	Gate-Body Leakage Current	V _{GS} = ±20V;V _{DS} = 0		±100	nA
I _{DSS}	Zero Gate Voltage Drain Current	V _{DS} = 650V; V _{GS} = 0 V _{DS} = 650V; V _{GS} = 0@T _J =125°C		100 1000	μА
V _{SD}	Forward On-Voltage	I _S = 35A; V _{GS} = 0		1.5	V



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